Docket No. 2

247099US8CONT

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Juni

Junji YOSHIDA, et al.

SERIAL NO: 10/748,159

GAU:

2828

FILED:

December 31, 2003

**EXAMINER:** 

FOR:

SEMICONDUCTOR LASER DEVICE, SEMICONDUCTOR LASER MODULE, AND OPTICAL FIBER

AMPLIFIER USING THE SEMICONDUCTOR LASER MODULE

## **INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.97**

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

Applicant(s) wish to disclose the following information.

#### REFERENCES

The applicant(s) wish to make of record the references cited in the attached European Search Report and listed on
the attached form PTO-1449. Copies of the listed references are attached, where required, as are either statements
of relevancy or any readily available English translations of pertinent portions of any non-English language
references.

☐ A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

#### **RELATED CASES**

Attached is a list of applicant's pending application(s), published application(s) or issued patent(s) which may be
related to the present application. In accordance with the waiver of 37 CFR 1.98 dated September 21, 2004, copies
of the cited pending applications are not provided. Cited published and/or issued patents, if any, are listed on the
attached PTO form 1449.

A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

#### **CERTIFICATION**

- ☐ Each item of information contained in this information disclosure statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this statement.
- □ No item of information contained in this information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned, having made reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this statement.

### **DEPOSIT ACCOUNT**

Please charge any additional fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit account number 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

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LIST OF REFERENCES CITED BY APPLICANT				APPLICANT				
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				FILING DATE		GROUP		
				December 31, 2003	2828			
				U.S. PATENT DOCUMENTS				
EXAMINER INITIAL	·	DOCUMENT NUMBER	DATE			FILING DATE APPROPRIATE		
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	AZ Additional References sheet(s) att				es sheet(s) attached			
Examiner				Date Co	onsidered			
*Examiner: I	nitial if	reference is considered,	whether or no	ot citation is in conformance with MPEP n with next communication to applicant	609; Draw	line through citati	on if not in	

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